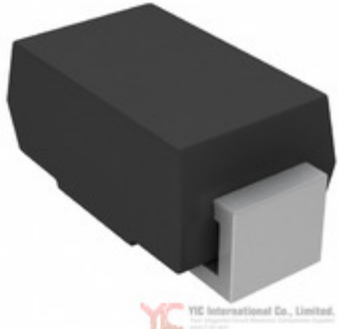

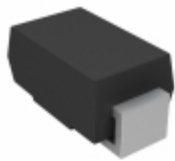
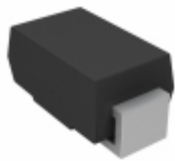
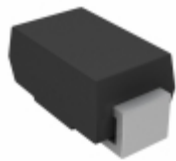

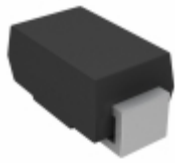
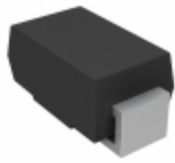
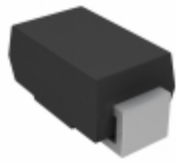
	<h2>S1KHE3/61T</h2>
	<p>Hersteller-Teilenummer: S1KHE3/61T</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: DIODE GEN PURP 800V 1A DO214AC</p> <p>Datenblätter: 1.S1KHE3/61T.pdf 2.S1KHE3/61T.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 7500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	S1KHE3/61T
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	DIODE GEN PURP 800V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	7500 pcs Stock
detaillierte Beschreibung	Diode Standard 800V 1A Surface Mount DO-214AC
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.1V @ 1A
Strom - Sperrleckstrom @ Vr	5µA @ 800V
Spannung - Sperr (Vr) (max)	800V
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	1.8µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	12pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)
Basisteilenummer	S1K
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

S1KHE3/61T ist neu im Original, Suche S1KHE3/61T Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S1KHE3/61T Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage S1KHE3/61T: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>S1KFSHMXG TSC (Taiwan Semiconductor) DIODE, 1A, 800V, AEC-Q101, SOD-1</p>	 <p>S1KHE3_A/H Electro-Films (EFI) / Vishay DIODE GEN PURP 800V 1A DO214AC</p>	 <p>S1KHE3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 800V 1A DO214AC</p>	 <p>S1KHE3_A/I Electro-Films (EFI) / Vishay DIODE GEN PURP 800V 1A DO214AC</p>
 <p>S1KFSHMWG TSC (Taiwan Semiconductor) DIODE, 1A, 800V, AEC-Q101, SOD-1</p>	 <p>S1KHE3/5AT Vishay / Semiconductor - Diodes Division DIODE GEN PURP 800V 1A DO214AC</p>	 <p>S1KHE3_A/I Vishay / Semiconductor - Diodes Division DIODE GEN PURP 800V 1A DO214AC</p>	 <p>S1KHE3_A/H Vishay / Semiconductor - Diodes Division DIODE GEN PURP 800V 1A DO214AC</p>

heiße Teile

Mehr

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D L0805150JEWTR	LT3570EUF#PBF	LYT4213E	NE3505M04-T2	OP-07DPS
PD7M440H	PH150F48-12	PT928-6B	RT9200-50CB.	S-8254BCHFT-TB-U
S1K-13-F	S1K-E3/61T	D S1K-E3/61T	S1K-M3/61T	S1K-M3/61T
S1K50023F00C2	D S1K50023F00C3	S1K60115B00A00	S1K60165F00B00	S1K75064B00A000
S1K75574B00C000	S1KA-E3/61T	S1KA-E3/61T	S1KB-13-F	S1KHE3/61T
S9S08DN48CLF	SD553C36S50L	SI4730-C40-ZM0R	SP1086V1-L	T589N17TOF
TC2105-2.8VCTTR	THN6501Z	UCC3872M	UMK105CH560JV-F	UMK105CJ030CV-F

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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